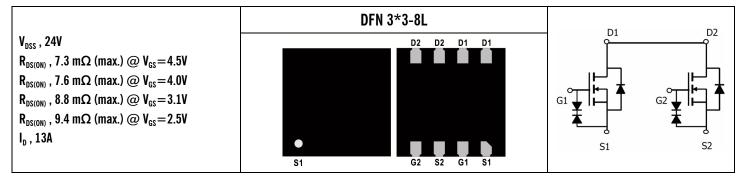


SG2402TD

24V COMMON-DRAINDUAL N-CHANNEL POWER MOSFET



Description	Features
The SG2402TD uses advanced trench technology to provide excellent $R_{\mbox{\tiny DS(ON)}}$	
low gate charge and operation with gate voltages as low as 1.8V. This device is	ESD Protection
suitable for use as a load switch or in PWM applications. It is ESD protected.	Applications
	Load Switch
	Battery Powered Systems

Ordering Information

Ordering Code	Marking Code	RoHS Status	Package	Package Code	Packing	Quantity
SG2402TD	2402TD	Halogen-Free	DFN 3*3-8L	TD	Tape&Reel	3,000

Absolute Maximum Ratings (T₄=25°C unless otherwise noted)

	Symbol	Value	Unit	
Drain-Source Voltage		V _{DS}	24	V
Gate-Source Voltage		V _{GS}	±12	V
Drain Current-Continuous T _A =25°C		Ι _D	13	А
Drain Current-Pulsed Note 1		I _{DM}	54	Α
Maximum Power Dissipation	Mounted on ceramic substrate (900mm ² x 0.8mm) 1 unit	P _D	1.4	W
Maximum rower Dissipation	Mounted on ceramic substrate (900mm ² x 0.8mm)	P _T	1.5	W
Storage Temperature Range		T _{stg}	-55 to +150	0°
Operating Junction Temperature	Range	Tj	-55 to +150	0°

Notes:

1. Pulse Test: Pulse Width $\leq 10\mu$ s, Duty Cycle $\leq 1\%$.

2. Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



Electrical Characteristics ($T_j = 25^{\circ}C$ unless otherwise noted)

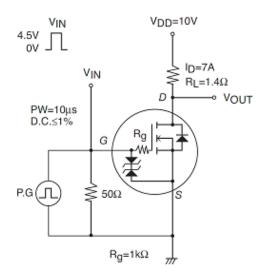
OFF CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS} = 0V, I_{DS} = 250 \mu A$	24	-	-	٧
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20V, V_{GS} = 0V$	-	-	1	μA
Gate-Body Leakage	I _{GSS}	$V_{GS} = \pm 8V, V_{DS} = 0V$	-	-	±5	μA

ON CHARACTERISTICS							
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Gate Threshold Voltage	V _{GS(TH)}	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	0.45	0.6	1.3	V	
	R _{ds(on)}	$V_{GS} = 4.5V, I_{DS} = 5.5A$	4.5	6.1	7.3		
Drain-Source On-State Resistance Note 1		$V_{GS} = 4.0V, I_{DS} = 5.5A$	4.7	6.4	7.6		
		$V_{GS} = 3.1V, I_{DS} = 5.5A$	5.2	7.3	8.8	mΩ	
		$V_{GS} = 2.5V, I_{DS} = 3.0A$	6.2	7.8	9.4]	

SWITCHING CHARACTERISTICS							
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Turn-On Delay Time	T _{d(on)}		-	0.56	-		
Rise Time	t,	$V_{DD} = 10V, I_{DS} = 7A, V_{GS} = 4.5V, R_g = 1K\Omega$ See Switching Time Test Circuit	-	0.54	-	1	
Turn-Off Delay Time	T _{d(off)}		-	19	-	μs	
Fall Time	t _f		-	22	-		
Total Gate Charge at 4.5V	Qg		-	13.2	-		
Gate to Source Gate Charge	Q _{gs}	$V_{DS} = 10V, I_{DS} = 13A, V_{GS} = 4.5V$	-	3.1	-	nC	
Gate to Drain "Miller" Charge	Q _{gd}		-	2.4	-		

DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS							
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain-Source Diode Forward Voltage	V _{SD}	$V_{GS} = 0V, I_{DS} = 13A$	-	0.7	1.2	٧	

Switching Time Test Circuit

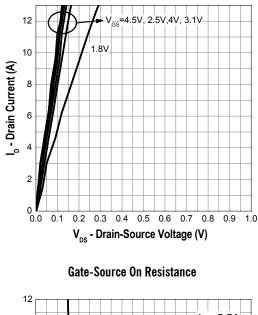


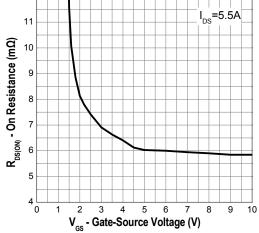


SG2402TD 24V COMMON-DRAIN DUAL N-CHANNEL POWER MOSFET

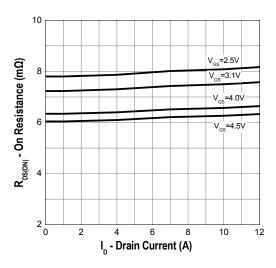
Typical Operating Characteristics

Output Characteristics

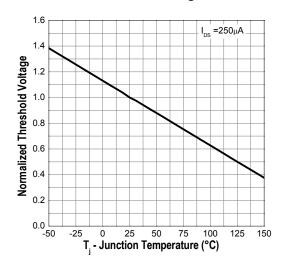




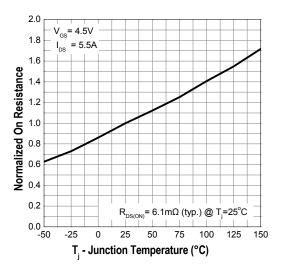
Drain-Source On Resistance



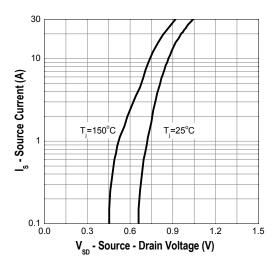
Gate Threshold Voltage



Drain-Source On Resistance



Source-Drain Diode Forward

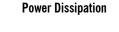


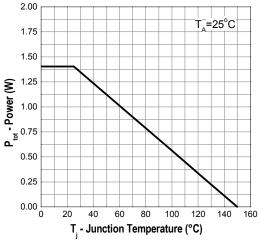
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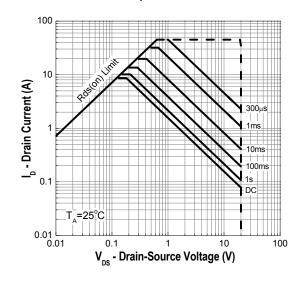
SG2402TD 24V COMMON-DRAINDUAL N-CHANNEL POWER MOSFET

Typical Operating Characteristics (Cont.)



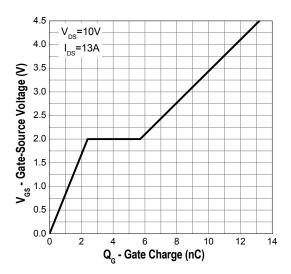


Safe Operation Area



Drain Current I_b - Drain Current (A) 8 7 6 T_{_}=25°C V_G=4.5V 0 L 0 T_i - Junction Temperature (°C)

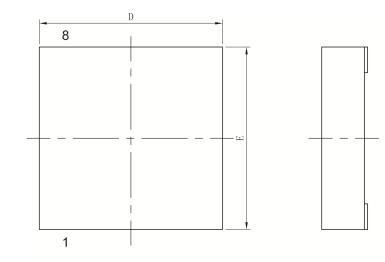


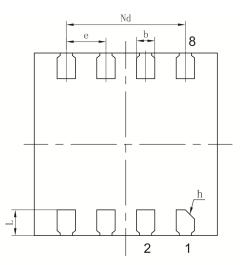




SG2402TD 24V COMMON-DRAIN DUAL N-CHANNEL POWER MOSFET

Package Outline

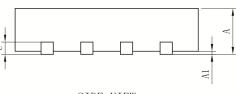




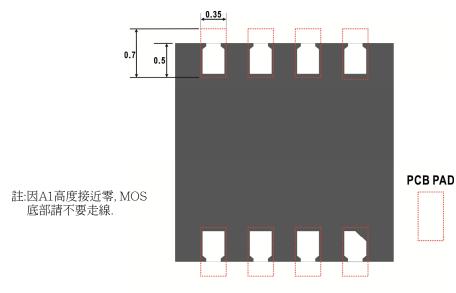
TOP VIEW

BOTTOM VIEW

SYMBOL	М	ILLIMETH	ER		
STWIDOL	MIN	NOM	MAX		
А	0.70	0.75	0.80		
A1	0.00	0.02	0.05		
b	0.25	0.30	0.35		
с	0.19	0.20	0.21		
D	2.90	3.00	3.10		
Nd	1.90	1.95	2.00		
Е	2.90	3.00	3.10		
e					
L	0.37	0.42	0.47		
h	0.10	0.15	0.20		
裁体尺寸 (mil)	102X84				



SIDE VIEW

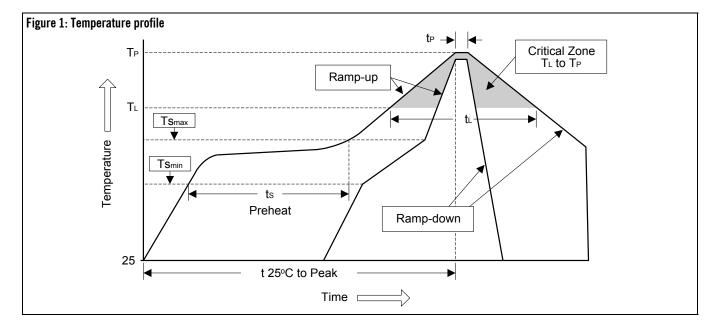


Finger Pad Layout recommend



Soldering Methods for SiliconGear's Products

- 1. Storage environment: Temperature = 10° C to 35° C Humidity = $65\% \pm 15\%$
- 2. Reflow soldering of surface-mount devices



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate $(T_L \text{ to } T_P)$	<3°C/sec	<3°C/sec
Preheat		
- Temperature Min (Ts _{min})	100°C	150°C
- Temperature Max (Ts _{max})	150°C	200°C
- Time (min to max) (ts)	60 to 120 sec	60 to 180 sec
Tsmax to T _L		
- Ramp-up Rate	<3°C/sec	<3°C/sec
Time maintained above:		
- Temperature (T _L)	183°C	217°C
- Time (t _L)	60 to 150 sec	60 to 150 sec
Peak Temperature (T _P)	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak	10 to 30 sec	20 to 40 sec
Temperature (t_P)	10 10 50 560	20 t0 40 Sec
Ramp-down Rate	<6°C/sec	<6°C/sec
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

3. Flow (wave) soldering (solder dipping)

Products	Peak Temperature	Dipping Time
Pb devices.	245°C ±5°C	$5 ext{sec} \pm 1 ext{sec}$
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec



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